

## **UHF Silicon FET Power Amplifiers**

Designed for 12.5 V UHF power amplifier applications in industrial and commercial FM equipment operating from 806 to 950 MHz.

• Specified 12.5 V Characteristics:

RF Input Power: ≤250 mW (MHW2821-1)

≤300 mW (MHW2821-2)

RF Output Power: 20 W (MHW2821-1)

18 W (MHW2821-2)

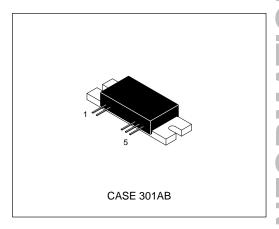
- LDMOS FET Technology
- Epoxy Glass Substrate Eliminates Possibility of Substrate Fracture
- 50 Ω Input/Output Impedance
- Guaranteed Stability and Ruggedness
- Cost Effective

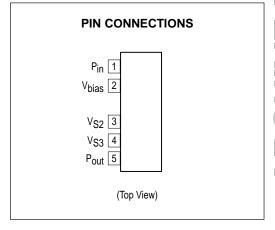
## Simplified Block Diagram This device contains 2 active transistors

## MHW2821-1 MHW2821-2

RF POWER AMPLIFIER 20 W, 806 to 870 MHz (-1 suffix) 18 W, 890 to 950 MHz (-2 suffix)

SEMICONDUCTOR TECHNICAL DATA





## **ORDERING INFORMATION**

Device	Operating Temperature Range	Package		
MHW2821-1	T <sub>Δ</sub> = -30 to 100°C	Power Module		
MHW2821-2	1A = -30 to 100 C	i ower wodule		

**MAXIMUM RATINGS** (Flange Temperature = 25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
DC Supply Voltages	V <sub>bias</sub> , V <sub>S2</sub> , V <sub>S3</sub>	12.5 16	Vdc
RF Input Power	Pin	400	mW
RF Output Power	P <sub>out</sub>	23	W
Operating Case Temperature Range	TC	-30 to 100	°C
Storage Temperature Range	T <sub>stg</sub>	-30 to 100	°C

NOTES: 1. Meets Human Body Model (HBM) ≤3000 V.

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (\forall_{S2} = \forall_{S3} = 12.5 \ \forall dc; \ \forall_{bias} = 12.5 \ \forall dc; \ T_{C} = 25^{\circ}C, \ 50 \ \Omega \ \text{system, unless otherwise noted.})$

Characteristic	Symbol	Min	Тур	Max	Unit
Frequency Range MHW2821–1 MHW2821–2	BW	806 890	_ _	870 950	MHz
Input Power  MHW2821-1 (P <sub>out</sub> = 20 W) [Note]  MHW2821-2 (P <sub>out</sub> = 18 W) [Note]	P <sub>in</sub>	_ _	_ _ _	250 300	mW
Power Gain  MHW2821-1 (P <sub>out</sub> = 20 W) [Note]  MHW2821-2 (P <sub>out</sub> = 18 W) [Note]	Gp	19 17.9	- -	_ _	dB
Efficiency (Rated P <sub>out</sub> )	η	35	-	-	%
Harmonics (Rated Pout Reference) [Note]	2f <sub>O</sub> 3f <sub>O</sub>	_ _	_	-40 -45	dBc
Input VSWR (Rated Pout) [Note]	VSWR <sub>in</sub>	-	-	3:1	-
Load Mismatch Stress (V <sub>Supply</sub> = 16 Vdc; P <sub>Out</sub> = 20 W for MHW2821–1; P <sub>Out</sub> = 18 W for MHW2821–2; Load VSWR = 20:1, All Phase Angles at Frequency of Test) [Note]	Ψ		No Degradation in Output Power Before and After Test  All Spurious Outputs More than 60 dB Below Desired Signal		•
Stability ( $V_{Supply}$ = 10.8 to 16 Vdc; $P_{in}$ = 0 to 250 mW for MHW2821–1; $P_{in}$ = 0 to 300 mW for MHW2821–2; Load VSWR = 4:1, All Phase Angles at Frequency of Test	-				
Quiescent Current (With No RF Applied, V <sub>S2</sub> = V <sub>S3</sub> = 12.5 Vdc; V <sub>bias</sub> = 12.5 Vdc)	I <sub>sq</sub>	-	_	500	mA
Leakage Current (With No RF Applied, V <sub>S2</sub> = V <sub>S3</sub> = 12.5 Vdc; V <sub>bias</sub> = 0 Vdc)	ΙL	_	_	0.6	mA
Bias P <sub>in</sub> Current (Rated P <sub>out</sub> ) [Note]	I <sub>bias</sub>	-	_	3.0	mA

 $\textbf{NOTE:} \quad \text{Adjust P}_{in} \text{ for specified P}_{out}.$ 

<sup>2.</sup> ESD data available upon request.

## MHW2821-1 MHW2821-2

Figure 1. Test Circuit Diagram Output Power Spectrum Meter Analyzer 1¢ 20 30 4 ¢ 5 🗘 Reflected Input Test Fixture Power Power Meter Meter C8 \_\_\_\_\_\_ C7 C5 C2 Z<sub>1</sub> 丰 Z<sub>2</sub> 20 dB Attenuator RF In RF Out 20 dB Dual 20 dB Dual **Directional Coupler Directional Coupler** V<sub>bias</sub> 12.5 V V<sub>S2</sub> 12.5 V V<sub>S3</sub> 12.5 V **-**VVV-Power 10 dB Termination C1, C2, C3 C4, C5, C6  $0.018 \mu F$ RF Signal Minimum 0.1 μF

1.0 μF 50  $\Omega$  Microstrip

C7, C8, C9 Z1, Z2

Generator

Attenuation

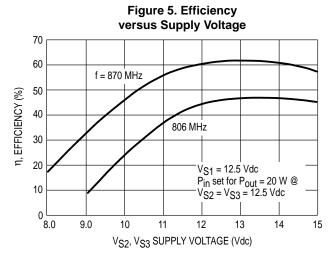
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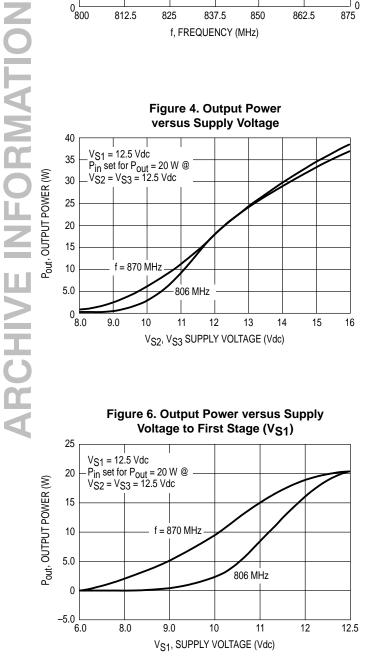
## MHW2821-1 MHW2821-2 **TYPICAL CHARACTERISTICS (MHW2821-1)**

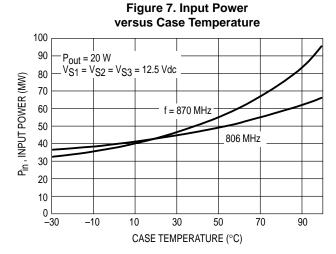
Figure 2. Input Power, Efficiency and VSWR versus Frequency 200 4.0 180 P<sub>out</sub> = 20 W 3.5 V<sub>S1</sub> = V<sub>S2</sub> = V<sub>S3</sub> = 12.5 Vdc P<sub>in</sub>(mW), η, ΕΓΓΙΟΙΕΝΟΥ (%) 160 3.0 140 120 100 80 Input VSWR:1 1.0 η 40 0.5 20 Pin (mW) 0 0800 812.5 825 837.5 862.5 875 f, FREQUENCY (MHz)

Figure 3. Output Power versus Input Power 35 806 MHz 30  $V_{S1} = V_{S2} = V_{S3} = 12.5 \text{ Vdc}$ Pout, OUTPUT POWER (W) 25 f = 870 MHz 20 15 10 5.0 20 30 40 70 125 175 Pin, INPUT POWER (mW)

Figure 4. Output Power versus Supply Voltage 40 V<sub>S1</sub> = 12.5 Vdc P<sub>in</sub> set for P<sub>out</sub> = 20 W @ \_V<sub>S2</sub> = V<sub>S3</sub> = 12.5 Vdc 35 25 f = 870 MHz 10 5.0 806 MHz 0.8 9.0 10 12 13 15 16 V<sub>S2</sub>, V<sub>S3</sub> SUPPLY VOLTAGE (Vdc)





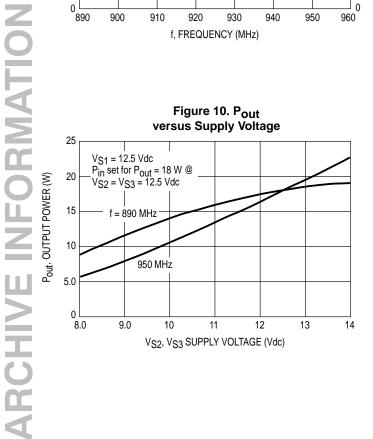


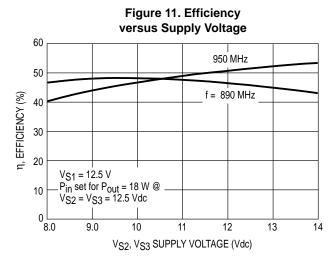
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## MHW2821-1 MHW2821-2 TYPICAL CHARACTERISTICS (MHW2821-2)

Figure 8. Pin VSWR, and Efficiency versus Frequency 200 3.5 180 P<sub>out</sub> = 18 W 3.0  $V_{S1} = V_{S2} = V_{S3} = 12.5 \text{ Vdc}$ in(mPW), n, EFFICIENCY (%) 160 2.5 140 2.0 S. INPUT VSWR Input VSWR:1 120 100 80 60 1.0 40 Pin (mW) 0.5 20 0 890 900 910 920 930 940 950 960 f, FREQUENCY (MHz)

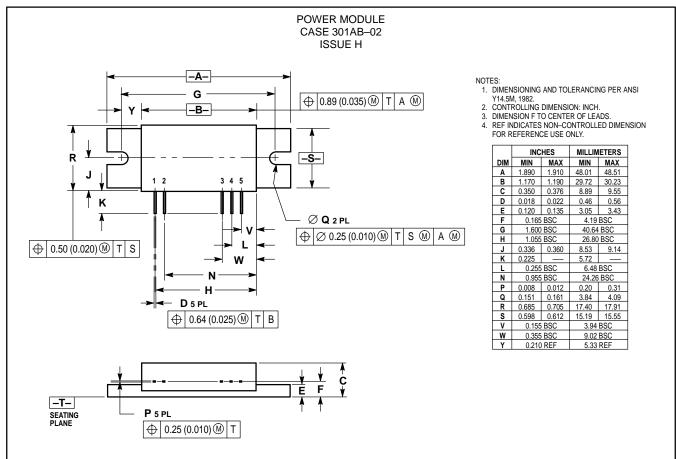
Figure 9. Output Power versus Input Power 30 V<sub>S1</sub> = V<sub>S2</sub> = V<sub>S3</sub> = 12.5 V 25 P<sub>out</sub>, OUTPUT POWER (W) f = 890 MHz 20 15 950 MHz 10 5.0 15 25 35 55 65 100 150 200 Pin, INPUT POWER (mW)





## MHW2821-1 MHW2821-2

## **OUTLINE DIMENSIONS**



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